

**UTC** UNISONIC TECHNOLOGIES CO., LTD

# **US301**

Preliminary

**CMOS IC** 

# 0.2A SINGLE CHANNEL CURRENT-LIMITED LOAD SWITCH

# DESCRIPTION

The UTC US301 is single channel current-limited integrated high-side power switches, optimized for hot-swap applications.

The US301 provides a complete protection solution for application subject to heavy capacitive loads and the prospect of short circuit. The devices have fast short-circuit response time for improving overall system robustness, and offer reverse-current blocking, over-current and over-temperature protection, as well as under-voltage lockout functionality. It also has controlled built-in soft-start time, typically 0.7 ms.

#### **FEATURES**

- \* Input voltage range: 2.7V~5.2V
- \* Short-circuit protection and fast response time
- \* Accurate current limiting: 0.4A
- \* On-resistance:250 mΩ
- \* Reverse-current blocking
- \* Soft-start with 0.7ms typical turn-on time
- \* Over-current and over-voltage protection
- \* Thermal protection
- \* Ambient temperature range: -40°C~+85°C

#### **ORDERING INFORMATION**

Ordering Number	Package	Packing
US301G-AE2-R	SOT-23-3	Tape Reel



### MARKING





# PIN CONFIGURATION



# PIN DESCRIPTION

PIN NO.	PIN NAME	DESCRIPTION
1	GND	GND
2	OUT	Switch output pin
3	IN	Voltage input pin



# ■ ABSOLUTE MAXIMUM RATING

PARAMETER	SYMBOL	RATINGS	UNIT
Input Voltage Relative to GND	V <sub>IN</sub>	6.5	V
Output Voltage Relative to GND	V <sub>OUT</sub>	V <sub>IN</sub> +0.3	V
Maximum Continuous Load Current	I <sub>LOAD</sub>	Internal Limited	А
Maximum Junction Temperature	TJ	150	°C
Storage Temperature Range (Note 4)	T <sub>STG</sub>	-65~150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. UL Recognized Rating from -30°C~70°C (Diodes qualified T<sub>ST</sub> from -65°C~150°C)

### RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input voltage relative to GND	V <sub>IN</sub>		2.7		5.2	V
Output Current	louт		0		0.2	А
Operating Ambient Temperature	TA		-40		+85	°C

## ■ ELECTRICAL CHARACTERISTICS (T<sub>A</sub>=25°C, V<sub>IN</sub>=+5.0V, unless otherwise stated)

PARAMETER	SYMBOL	TEST CONDITIONS (Note 1)	MIN	TYP	MAX	UNIT
Input UVLO	V <sub>UVLO</sub>	V <sub>IN</sub> rising	2.35		2.90	V
Input Quiescent Current	lq	Above UVLO, I <sub>OUT</sub> =0		85	125	μA
Reverse Leakage Current	I <sub>REV</sub>	$V_{IN}$ =0V, $V_{OUT}$ =5V, $I_{REV}$ at $V_{IN}$		0.01	0.10	μA
Switch On-Resistance	R <sub>DS(ON)</sub>	V <sub>IN</sub> =5V, I <sub>OUT</sub> =0.2A	100	250	350	mΩ
Over-Load Current Limit	I <sub>LIMIT</sub>	V <sub>IN</sub> =5V, V <sub>OUT</sub> =4V	0.2	0.4	0.5	А
Short-Circuit Current	l <sub>os</sub>	OUT shorted to ground	0.2	0.4	0.5	Α
Reverse-Current Trigger Point	I <sub>ROCP</sub>	V <sub>IN</sub> =5.0V, V <sub>OUT</sub> =5.2V		0.20	0.25	А
Deglitch Time from Reverse Current Trigger to MOSFET Turn Off	T <sub>TRIG</sub>	(Note 2)	0.5	0.7	1.0	ms
Output Over-Voltage Trip Point	V <sub>OVP</sub>	(Note 3)	5.2		5.6	V
Debounce Time From Output Over-Voltage to MOSFET Turn Off	T <sub>OVP</sub>			15		μs
Recovery After Turn-Off from ROCP and OVP	$V_{\text{REC}}$			101%		V <sub>IN</sub>
Output turn-on time (Note 4)	T <sub>ON</sub>	C <sub>L</sub> =0.1μF, R <sub>LOAD</sub> =20Ω (UVLO to 90% V <sub>OUT-NOM</sub> )		0.7		ms
Thermal Shutdown Threshold	T <sub>SHDN</sub>	V <sub>IN</sub> =2.7V~5.2V		150		°C
Thermal Shutdown Hysteresis	T <sub>HYS</sub>			20		°C
Thermal Resistance Junction-to-Ambient (Note 5)	$\theta_{JA}$			215		°C/W

Notes: 1. Pulse-testing techniques maintain junction temperature close to ambient temperature; thermal effects must be taken into account separately.

- 2. When reverse current triggers at I<sub>ROCP</sub>=0.20A, the reverse current is continuously clamped at I<sub>ROCP</sub> for 0.7ms deglitch time until MOSFET is turned off.
- 3. During output over-voltage protection, the output draws approximately  $60\mu A$  current.
- Since the output turn-on slew rate is dependent on input supply slew rate, this limit is only applicable for input supply slew rate between V<sub>IN</sub>/0.2ms to V<sub>IN</sub>/1ms.
- 5. Device mounted on FR-4 substrate PCB, 2oz copper, with minimum recommended pad layout.



# TYPICAL APPLICATION CIRCUIT



UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.

